4V Drive Nch+Nch MOSFET

MP6K61

Structure

Silicon N-channel MOSFET

Features

- 1) Low on-resistance.
- 2) Built-in G-S Protection Diode.

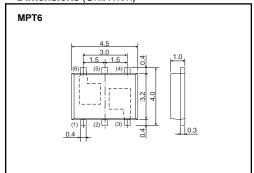
Application

Switching

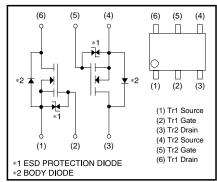
Packaging specifications

	Package	Taping
Type	Code	TR
	Basic ordering unit (pieces)	1000
MP6K61		0

●Dimensions (Unit:mm)



●Equivalent circuit



A protection diode is included between the gate and the source terminals to protect the diode against static electricity when the product is in use. Use the protection circuit when the fixed voltages are exceeded.

● Absolute maximum ratings (Ta=25°C)

<It is the same ratings for the Tr1 and Tr2.>

Parameter		Symbol	Limits	Unit	
Drain-source voltage		V_{DSS}	30	V	
Gate-source voltage		V _{GSS}	±20	V	
Drain current	Continuous	ID	±5.0	Α	
	Pulsed	I _{DP} *1	±20	Α	
Source current (Body diode)	Continuous	Is	1.6	Α	
	Pulsed	I _{SP} *1	20	Α	
Total power dissipation		*2 Pp	2.0	W/TOTAL	
		י ו	1.4	W/ELEMENT	
Channel temperature		Tch	150	°C	
Range of storage temperature		Tstg	-55 to +150	°C	

^{*1} Pw≤10μs, Duty cycle≤1% *2 MOUNTED ON A CERAMIC BOARD.

●Electrical characteristics (Ta=25°C)

<It is the same characteristics for the Tr1 and Tr2.>

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Gate-source leakage	Igss	-	-	±10	μΑ	V _{GS} =±20V, V _{DS} =0V
Drain-source breakdown voltage	V _(BR) DSS	30	-	_	V	I _D =1mA, V _{GS} =0V
Zero gate voltage drain current	IDSS	-	-	1	μΑ	V _{DS} =30V, V _{GS} =0V
Gate threshold voltage	VGS (th)	1.0	-	2.5	V	VDS=10V, ID=1mA
Static drain-source on-state resistance	R _{DS} (on)	-	36	51	mΩ	I _D =5.0A, V _{GS} =10V
		-	50	70		I _D =5.0A, V _{GS} =4.5V
		-	55	77		I _D =5.0A, V _{GS} =4.0V
Forward transfer admittance	Yfs *	3.0	-	-	S	ID=5.0A, VDS=10V
Input capacitance	Ciss	-	460	_	pF	V _{DS} =10V
Output capacitance	Coss	-	80	_	pF	V _{GS} =0V
Reverse transfer capacitance	Crss	_	60	_	pF	f=1MHz
Turn-on delay time	t d (on) *	-	10	_	ns	I _D =2.5A, V _D D ≒15V
Rise time	tr *	-	20	_	ns	V _{GS} =10V
Turn-off delay time	t _{d (off)} *	-	25	_	ns	R _L =6.0Ω
Fall time	t _f *	-	5	_	ns	$R_G=10\Omega$
Total gate charge	Qg *	_	4.0	_	nC	ID=5.0A, VDD≒15V
Gate-source charge	Q _{gs} *	_	1.8	_	nC	V _{GS} =5V
Gate-drain charge	Q _{gd} *	-	1.5	_	nC	$R_L=3.0\Omega$, $R_G=10\Omega$

^{*}Pulsed

●Body diode characteristics (Source-Drain) (Ta=25°C) < It is the same characteristics for the Tr1 and Tr2.>

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Forward voltage	Vsp*	_	_	1.2	V	Is=5.0A. Vgs=0V

ROHM

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^{*}Pulsed

Electrical characteristic curves

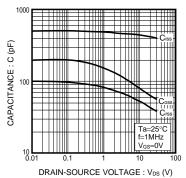


Fig.1 Typical Capacitance

vs. Drain-Source Voltage

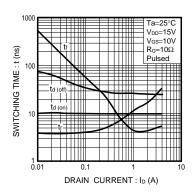


Fig.2 Switching Characteristics

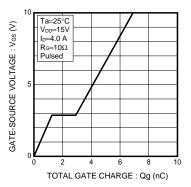


Fig.3 Dynamic Input Characteristics

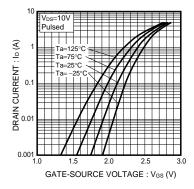


Fig.4 Typical Transfer Characteristics

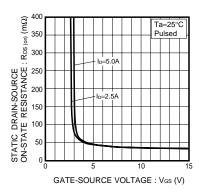


Fig.5 Static Drain-Source On-State Resistance vs. Gate-Source Voltage

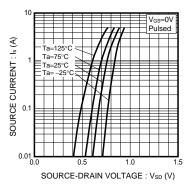


Fig.6 Source Current vs. Source-Drain Voltage

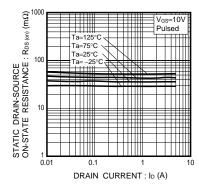


Fig.7 Static Drain-Source On-State Resistance vs. Drain Current (I)

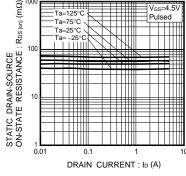


Fig.8 Static Drain-Source On-State Resistance vs. Drain Current (II)

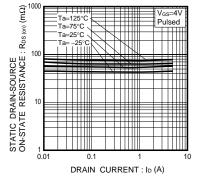
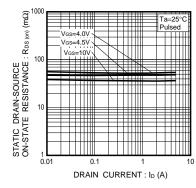


Fig.9 Static Drain-Source On-State Resistance vs. Drain Current (III)



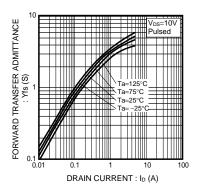


Fig.10 Static Drain-Source On-State Resistance vs. Drain Current (IV)

Fig.11 Forward Transfer Admittance vs. Drain Current

•Electrical characteristic curves

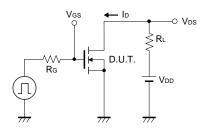


Fig.12 Switching Time Test Circuit

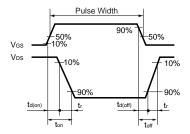


Fig.13 Switching Time Waveforms

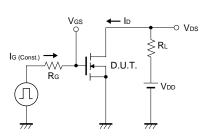


Fig.14 Gate Charge Test Circuit

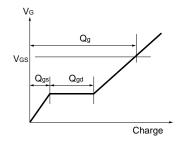


Fig.15 Gate Charge Waveform

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